## NSN 5961-00-765-6071

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breakdown voltage, collector-to-emitter, base open and 5.0 breakdown

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Inclosure Material:
Metal
Overall Length:
0.210 inches
Terminal Length:
0.500 inches
Overall Diameter:
0.230 inches
Internal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Terminal
Terminal Circle Diameter:
0.100 inches
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
50.0 breakdown voltage, collector-to-base, emitter open and 40.0
voltage, emitter-to-base, collector open
Current Rating Per Characteristic:
200.00 milliamperes source cutoff current
Power Rating Per Characteristic:
360.0 milliwatts small-signal input power, common-collector
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
Junction pattern arrangement: pnp
Terminal Type And Quantity:
3 uninsulated wire lead
Specification Data:
80131-release4694 professional/industrial association specification
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No 
Fiig:

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